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Electronic Patent Application Submission

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EFS ID: 56558
Application ID: 10723547 
Title of Invention: A Vertical Replacement-Gate
Junction Field-Effect Transistor
First Named Inventor: Samir Chaudhry
Domestic/Foreign Application: Domestic Application
Filing Date: 2003-11-26
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Statement
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TRANSMITTAL

Electronic Version v1.1
Stylesheet Version v1.1.0

Title of Invention	A Vertical Replacement-Gate Junction Field-Effect Transistor	
Application Number:	10/723547	
Date:	2003-11-26	
First Named Applicant:	Samir Chaudhry	
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Submitted by:	Elec. Sign.	Sign. Capacity
John L. DeAngelis Jr. Registered Number: 30,622	/John L. DeAngelis, Jr./	Attorney
Documents being submitted us-ids	Files Agere285-usidst.xml us-ids.dtd us-ids.xsl	
Comments		



ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0

Title of Invention	A Vertical Replacement-Gate Junction Field-Effect Transistor
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Confirmation Number: 9745

First Named Applicant: Samir Chaudhry

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Art Unit: 2811

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or 6133099 or 6197641 or 5866925 or
5889298).pn.

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
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	2	5599724	1997-02-04	Yoshida			
	3	5414289	1995-05-09	Fitch, et al			
	4	5576238	1996-11-19	Fu			
	5	5668391	1997-09-16	Kim, et al			
	6	5744846	1998-04-28	Batra, et al			
	7	6297531	2001-10-02	Armacost, et al			
	8	4366495	1982-12-28	Goodman, et al			
	9	4455565	1984-06-19	Goodman, et al			
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	11	4683643	1987-08-04	Nakajima, et al			
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	19	5866925	1999-02-02	Zolper, et al
	20	5889298	1999-03-30	Plumton, et al

Signature

Examiner Name	Date